

### Description

The LMV331/LMV393 series are low-voltage, (2.7V to 5.5V) single and dual comparators, which are designed to effectively reduce cost and space at low-voltage levels.

These devices offer specifications that meet or exceed the familiar LM331/LM393 devices operating with a lower supply voltage and consuming a far lower supply current.

The LMV331 is available in 5-Pin SOT353/SOT25 packages that reduce space on PC boards and portable electronic devices. LMV393 is available in industry standard SOP-8 and MSOP-8 packages.

#### Features

- Guaranteed 2.7V and 5.5V performance
- Operating temperature range (-40°C to +125°C)
- Low supply current 40 µA/comparator Typ
- Input Common Mode Voltage Range includes ground
- Open Collector Output for Maximums Flexibility
- SOT353, SOT25, MSOP-8, SO-8: Available in "Green" Molding Compound (No Br, Sb)
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

#### Pin Assignments



#### SOT25/SOT353



### SO-8/MSOP-8

#### Applications

- Mobile Communications
- Battery Powered Devices
- Notebooks and PDA's
- General Purpose Low-Voltage Applications
- General Purpose Portable Devices
- Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
  - 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  - 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

# Schematic Diagram



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### **Pin Descriptions**

LMV331	_MV331				
Pin Name	Pin #	Function			
IN+	1	Non-Inverting Input			
V <sub>EE</sub>	2	Chip Supply Voltage(Negative)/GND			
IN-	3	Inverting Input			
OUT	4	Output			
V <sub>cc</sub>	5	Chip Supply Voltage(Positive)			
LMV393					
10UT	1	Channel 1 Output			
1IN-	2	Channel 1 Inverting Input			
1IN+	3	Channel 1 Non-inverting Input			
V <sub>EE</sub>	4	Chip Supply Voltage(Negative)/GND			
2IN+	5	Channel 2 Non-inverting Input			
2IN-	6	Channel 2 Inverting Input			
2OUT	7	Channel 2 Output			
V <sub>CC</sub>	8	Chip Supply Voltage(Positive)			

### Absolute Maximum Ratings (Note 4) (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Symbol	Description		Rating	Unit
ESD HBM	Human Body Model ESD Protection		6.0	KV
ESD MM	Machine Model ESD Protection		200	V
V <sub>ID</sub>	Differential Input Voltage		±Supply Voltage	V
V <sub>CC</sub> -V <sub>EE</sub>	Supply Voltage		5.5	V
	Thermal Resistance Junction-to- Ambient	SOT353 (Note 5)	371	
0		SOT25 (Note 5)	204	°C/W
θ <sub>JA</sub>		SO-8 (Note 5)	120	C/W
		MSOP-8 (Note 5)	180	
T <sub>ST</sub>	Storage Temperature		-65 to +150	°C
TJ	Maximum Junction Temperature		+150	°C

 Stresses greater than the 'Absolute Maximum Ratings' specified above, may cause permanent damage to the device. These are stress ratings only; functional operation of the device at these or any other conditions exceeding those indicated in this specification is not implied. Device reliability may be effected by exposure to absolute maximum rating conditions for extended periods of time.
All numbers are typical, and apply for packages soldered directly onto a PC board in still air. Notes:

# Recommended Operating Conditions (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Symbol	Description	Rating	Unit
V <sub>CC</sub> -V <sub>EE</sub>	Supply Voltage	2.7 to 5.5	V
T <sub>A</sub>	Operating Ambient Temperature Range	-40 to +125	°C





# **Electrical Characteristics** (Notes 6 & 7) ( $@T_A = +25^{\circ}C$ , $V_{EE} = 0V$ , $V_{CM} = 0V$ and $R_L = 5.1K\Omega$ , unless otherwise specified.)

Symbol	Parameter		Test Conditions	Min	Тур	Max	Unit
-	rical Characteristic	S	· ·				•
Vos	Input Offset Volta	ge	-	-	1.7	7	mV
TCV <sub>OS</sub>			T <sub>A</sub> = full range	-	5	-	μV/°C
			-	-	10	250	
IB	Input Bias Curren	t	T <sub>A</sub> = full range	-	_	400	nA
			-	-	5	50	
los	Input Offset Curre	ent	T <sub>A</sub> = full range	-	_	150	nA
V <sub>CM</sub>	Common-Mode Ir	put Voltage Range		-0.1	_	+2.0	V
VSAT	Saturation Voltage		I <sub>SINK</sub> ≤ 1mA	-	120	-	mV
IO	Output Sink Curre		V <sub>0</sub> ≤ 1.5V	5	23	-	mA
i0	Output Onik Ourie		V0=1.0V	-	0.003	-	110.0
IOL	Output Leakage C	Current	T <sub>A</sub> = full range	-	0.000	1	μA
		LMV331		-	40	100	μA
Is		LMV393	-		40	100	μΛ
13	Cupply Current	(Both Comparators)	-	-	70	150	uA
7V AC Electr	rical Characteristic						
			Input overdrive= 10mV	-	1,000	-	ns
<b>t</b> PHL	Propagation delay	y high to low	Input overdrive= 100mV	-	350	-	ns
	<b>D</b> (1)   1		Input overdrive= 10mV	-	500	-	ns
t <sub>PLH</sub> Propagation delay low to high		Input overdrive= 100mV	-	400	-	ns	
/ DC Electric	al Characteristics						
	Input Offset Voltage		-	-	1.7	7	mV
Vos			T <sub>A</sub> = full range	-	-	9	
TCV <sub>OS</sub>	Input Offset Voltage Average Drift		T <sub>A</sub> = full range	-	5	-	μV/°C
	Input Bias Current		-	-	25	250	
IB			$T_A = $ full range	-	-	400	nA
				-	2	50	nA
los	Input Offset Curre	ent	T <sub>A</sub> = full range	-	-	150	
V <sub>CM</sub>	Common-Mode Ir	nput Voltage Range	-	-0.1	_	4.2	V
Av		erential Voltage Gain	_	20	50	-	V/mV
7.0	Largo Orginal Dire	Solution voltage Call	I <sub>SINK</sub> ≤ 4mA	-	200	400	mV
$V_{\text{SAT}}$	Saturation Voltag	e	$I_{SINK} \le 4$ mA, $T_A = full$ range	-	-	700	
lo	Output Sink Curre	ent	V <sub>0</sub> ≤ 1.5V	10	84	-	mA
			-	-	0.003	-	μΑ
IOL	Output Leakage (	Current	T <sub>A</sub> = full range	-	-	1	
			-	-	60	120	
		LMV331	T <sub>A</sub> = full range	-	-	150	μA
ls	Supply Current	LMV393	-	-	100	200	1
	(Both Comparators)		T <sub>A</sub> =full range	-	-	250	uA
AC Electric	al Characteristics	, , , , , , , , , , , , , , , , , , ,			1	_00	1
			Input overdrive = 10mV	-	600	-	ns
t <sub>PHL</sub>	Propagation delay	y high to low	Input overdrive = 100mV	-	200	-	ns
	<b>_</b>		Input overdrive = 10mV	-	450	-	ns
t <sub>PLH</sub>	Propagation delay low to high		Input overdrive = 100mV		300	-	ns

Notes: 6. Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration. The typical values are not tested and are not guaranteed on shipped production material. 7. All limits are guaranteed by testing or statistical analysis.



## Typical Performance Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)







# Typical Performance Characteristics (continued) (@ T<sub>A</sub> = +25°C, unless otherwise specified.)



**Propagation Delay vs. Temperature** 



Propagation Delay vs. Load Capacitors



**Output Voltage vs. Output Sink Current** 



#### Propagation Delay vs. Input Overdrive Voltage



Saturation Voltage vs. Temperature



**Output Voltage vs. Output Sink Current** 



### Typical Performance Characteristics (cont.) (@ T<sub>A</sub> = +25°C, unless otherwise specified.)





**Response Time for Negative Transition** 



**Response Time for Positive Transition** 





V<sub>cc</sub>=5V,<sup>U</sup>R<sub>L</sub>=5.1KΩ

Input Overdrive Voltage=100mV

100kHz Response

Input

Output<sub>2</sub>

# Typical Performance Characteristics (cont.) (@ T<sub>A</sub> = +25°C, unless otherwise specified.)



500kHz Response



### **Application Information**

#### **Detailed Description**

LMV331/LMV393 are low-voltage single/dual general- purpose comparators. They have a single supply operating voltage range from 2.7V to 5.5V; the common mode input voltage range extends from -0.1V below the negative supply to within 0.8V of the positive supply.

The LMV331/393 series is built using the BiCMOS process with bipolar input and output stages for improved noise performance. It is a costeffective solution for portable consumer products where space, low voltage, low power and price are the primary specification in circuit design.

#### **Basic Comparator**

A basic comparator circuit is used for converting analog signal to digital output. The LMV331/393 has open-collector output structure, which required a pull-high resistor to positive supply voltage for the output to switch properly. When the internal output transistor is off, the output voltage will be pulled up to the external positive voltage.

The output pull- up resistor should be chosen high enough so as to avoid excessive power dissipation, yet low enough to supply enough drive to switch whatever load circuitry is used on the comparator output. On the LMV331/393 the pull-up resistor should range between  $1K\Omega$  to  $10K\Omega$ .



#### Power Supply Bypassing

For better performance, power supply bypass capacitor is necessary. For a single-supply operation system, a minimum of 0.1µF bypass capacitor should be recommended to place as close as possible between V<sub>cc</sub> pin and GND.





# **Typical Application Circuit**





### **Ordering Information**



Part Number Pa	Paakaga Cada Paakaging	7"/13" Tape and Reel		
Fart Number	Package Code	Packaging	Quantity	Part Number Suffix
LMV331W5-7	W5	SOT25	3,000/Tape & Reel	-7
LMV331SE-7	SE	SOT353	3,000/Tape & Reel	-7
LMV393S-13	S	SO-8	2,500/Tape & Reel	-13
LMV393M8-13	M8	MSOP-8	2,500/Tape & Reel	-13

### **Marking Information**





Device	Package type	Identification Code
LMV331W5	SOT25	CX
LMV331SE	SOT353	CY

(2) SO-8

(3) MSOP-8



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# Package Outline Dimensions (All dimensions in mm.)

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

(1) Package Type: SOT25



	SOT25			
Dim	Min	Max	Тур	
Α	0.35	0.50	0.38	
в	1.50	1.70	1.60	
с	2.70	3.00	2.80	
D	_	_	0.95	
н	2.90	3.10	3.00	
J	0.013	0.10	0.05	
κ	1.00	1.30	1.10	
1	0.35	0.55	0.40	
М	0.10	0.20	0.15	
Ν	0.70	0.80	0.75	
α	0°	8°	_	
All D	All Dimensions in mm			

(2) Package Type: SOT353



	SOT353				
Dim	Min	Max	Тур		
Α	0.10	0.30	0.25		
В	1.15	1.35	1.30		
С	2.00	2.20	2.10		
D	0.65 Typ				
F	0.40	0.45	0.425		
Н	1.80	2.20	2.15		
J	0	0.10	0.05		
κ	0.90	1.00	1.00		
L	0.25	0.40	0.30		
Μ	0.10	0.22	0.11		
α	0°	8°	-		
All	All Dimensions in mm				



### **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

#### (1) Package Type: SOT25



Dimensions	Value (in mm)
Z	3.20
G	1.60
Х	0.55
Y	0.80
C1	2.40
C2	0.95

(2) Package Type: SOT353



Dimensions	Value (in mm)
Z	2.5
G	1.3
Х	0.42
Y	0.6
C1	1.9
C2	0.65



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